



41

2818

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

GERT BURBACH
FRANK HEINLEIN
JOHANNES GROSCHOPF
HARTMUT RUELKE
CARSTEN HARTIG

Examiner: R. Berry

Group Art Unit: 2818

Att'y Docket: 2000.064400/DE0058

Serial No.: 09/848,718

Filed: May 3, 2001

For: METHOD OF FORMING A SUBSTRATE
CONTACT IN A FIELD EFFECT
TRANSISTOR FORMED OVER A
BURIED INSULATOR LAYER

PATENT
RECEIVED
SEP 16 2003
TECHNOLOGY CENTER 2800

RESPONSE TO OFFICE ACTION DATED JUNE 20, 2003

CERTIFICATE OF MAILING 37 C.F.R. 1.8	
I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on the date below:	
<u>09/10/03</u> Date	<u>Kathryn Hares</u> Signature

Commissioner for Patents

Sir:

This paper is submitted in response to the Office Action dated June 20, 2003, for which the three-month date for response is Monday, September 22, 2003.

It is believed that no fee is due; however, should any fees under 37 C.F.R. §§ 1.16 to 1.21 be required for any reason, the Assistant Commissioner is authorized to deduct said fees from **Advanced Micro Devices, Inc.'s Deposit Account 01-0365/DE0058.**

Reconsideration of the application is respectfully requested.

Serial No. 09/848,718